NSN 5961-01-235-2197

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View Online at https://aerobasegroup.com/nsn/5961-01-235-2197 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and quality assurance level s **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/301 government specification Shelf Life:

Voc. domil/mli

N/a

Unit Of Measure:

Demilitarization:

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